



Features:

- RoHS Compliant
- 150 Watts
- DC 3.0 GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Chip Termination 150 Watts, 50Ω

Description

The A150N50X4C is high performance Aluminum Nitride (AIN) chip termination intended as a cost competitive alternative to Beryllium Oxide (BeO). It is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators, and for use in power combiners. The termination is also RoHS compliant!

General Specifications

Resistive Element Thick film
Substrate AIN Ceramic

Terminal Finish Matte Tin over Nickel Barrier

Operating Temperature -55 to +150°C (see de rating chart)

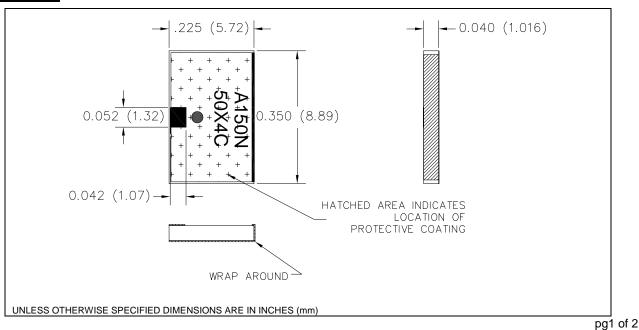
Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions in inches.

Electrical Specifications

Resistance Value:50 Ohms, \pm 2%Power:150 WattsFrequency Range:DC - 3.0 GHzReturn Loss>26dB

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

Outline Drawing

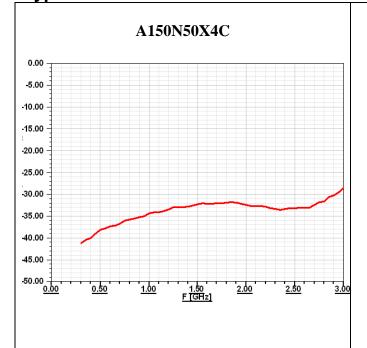


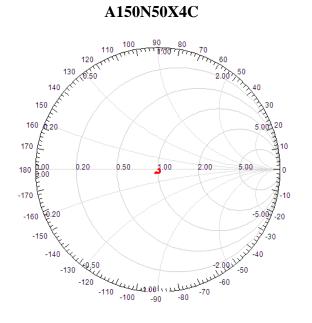
USA/Canada: (315) 432-8909 Toll Free: (800) 544-2414 Europe: +44 2392-232392



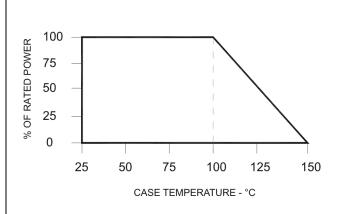


Typical Performance:



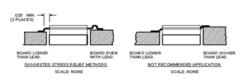


Power De-rating:



*Actual performance could be limited by the solder properties of the application

Suggested Mounting procedures:



SUGGESTED MOUNTING PROCEDURE

- MAKE SURE THAT THE DEVICES ARE MOUNTED ON FLAT SURFACES (.001" UNDER THE DEVICE) TO OPTIMIZE THE HEAT TRANSFER.
- POSITION DEVICE ON MOUNTING SURFACE AND SOLDER IN PLACE USING AN APPROPRIATE SOLDER.
- SOLDER LEADS IN PLACE USING AN APPROPRIATE SOLDER TYPE WITH A CONTROLLED TEMPERATURE IRON.

pg2 of 2

USA/Canada: (315) 432-8909 Toll Free: (800) 544-2414 Europe: +44 2392-232392

